

TOSHIBA Infrared LED GaAlAs Infrared Emitter

# TLN238(F)

Lead(Pb)-Free  
Space-Optical-Transmission  
Opto-Electronic Switches  
Printers, Fax Machines  
Home Electric Equipment

Unit: mm

- High radiant intensity: 70 mW/sr (typ.) at  $I_F = 50$  mA
- Half-angle value:  $\theta_{1/2} = \pm 18^\circ$  (typ.)
- High-speed data transmission purposes

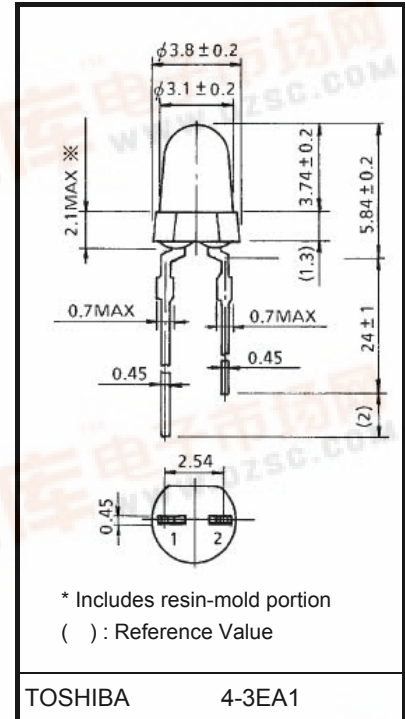
### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Forward current	$I_F$	100	mA
Pulse forward current	$I_{FP}$	1000 (Note 1)	mA
Power dissipation	$P_D$	200	mW
Reverse voltage	$V_R$	4	V
Operating temperature range	$T_{opr}$	-25~85	°C
Storage temperature range	$T_{stg}$	-30~100	°C
Soldering temperature (5 s), (Note 2)	$T_{sol}$	260	°C

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

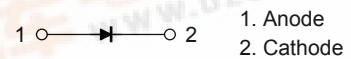
Note 1:  $f = 100$  kHz, duty = 1%

Note 2: Soldering must be performed 2 mm from the bottom of the package body.



Weight: 0.14 g (typ.)

### Pin Connection



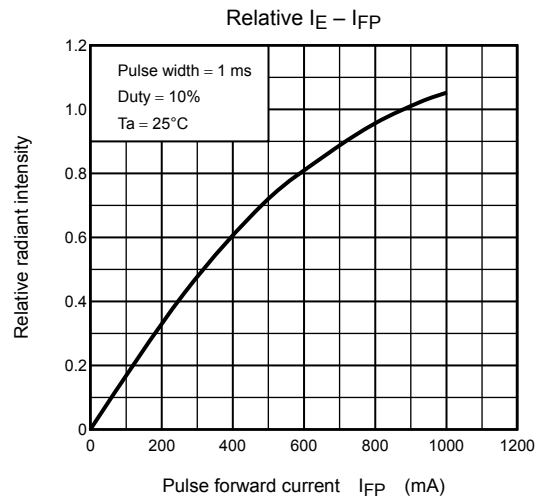
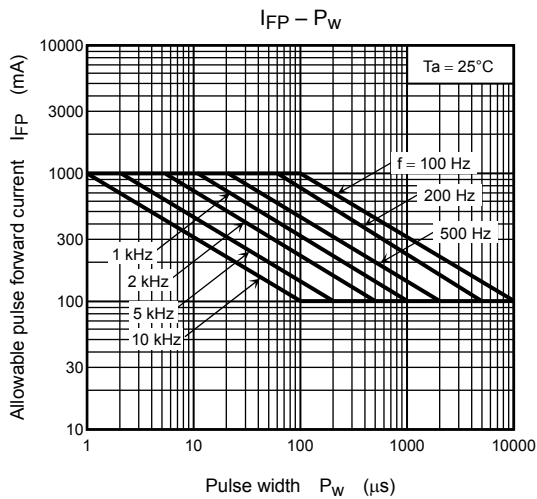
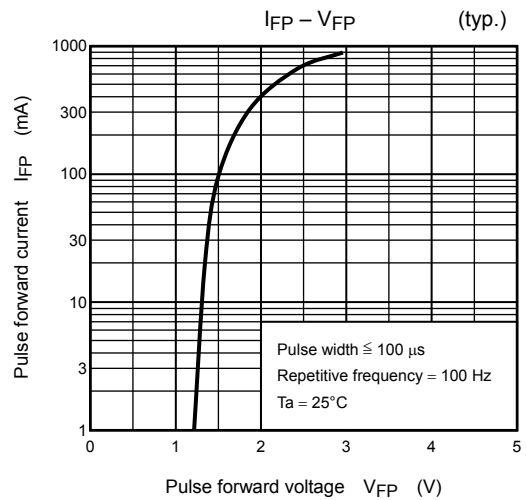
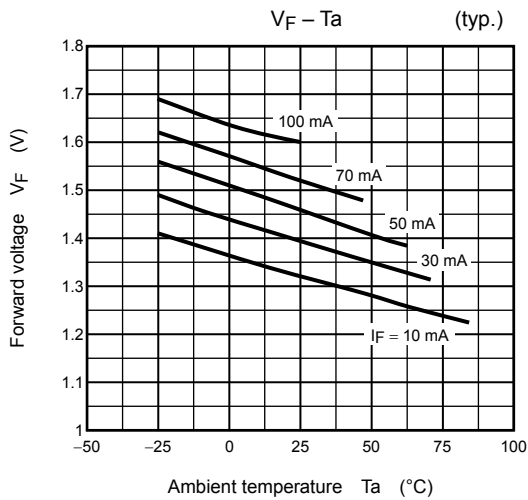
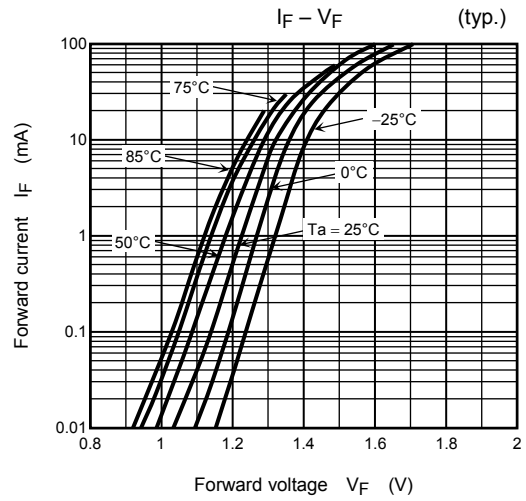
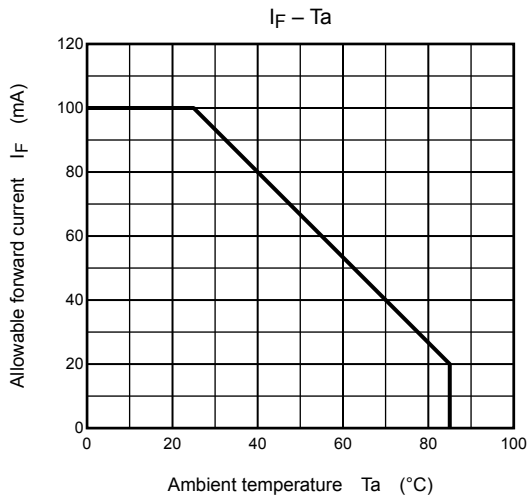
## Optical and Electrical Characteristics (Ta = 25°C)

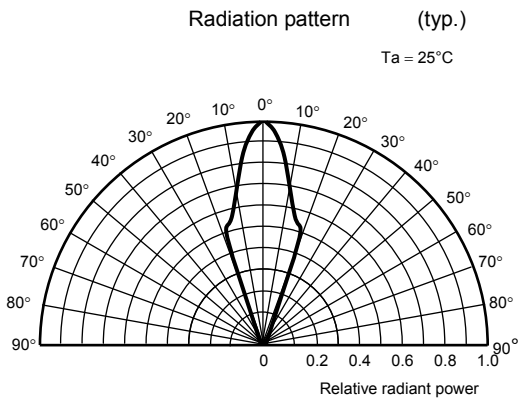
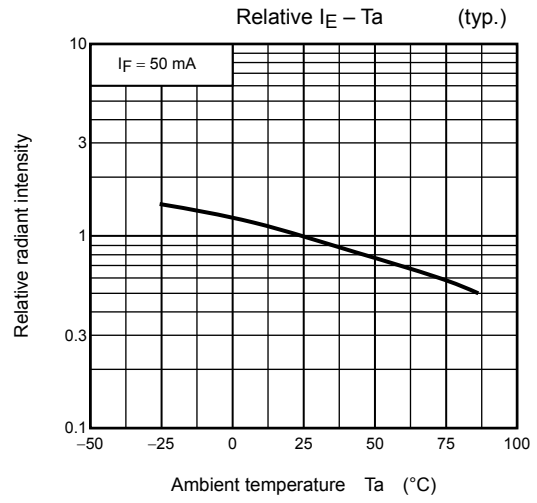
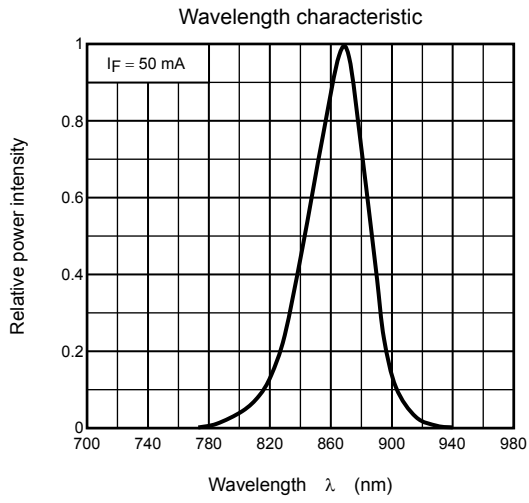
Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Forward voltage	$V_F$	$I_F = 100 \text{ mA}$	—	1.6	2.0	V
Reverse current	$I_R$	$V_R = 4 \text{ V}$	—	—	60	$\mu\text{A}$
Radiant intensity	$I_E$	$I_F = 50 \text{ mA}$	40	70	—	mW/sr
Cut-off frequency	$f_c$	$I_F = 50 \text{ mA} + 5 \text{ mA}_{P-P}$ (Note 3)	—	15	—	MHz
Peak emission wavelength	$\lambda_P$	$I_F = 50 \text{ mA}$	—	870	—	nm
Half-angle value	$\theta \frac{1}{2}$	$I_F = 50 \text{ mA}$	—	$\pm 18$	—	°

Note 3: This is the frequency when modulation light power decreases by 3 dB from 1 MHz.

## Handling Precautions

- Soldering must be performed under the stopper.
- When forming the leads, bend each lead at least 5 mm from the package body. Soldering must be performed after the leads have been formed.
- The radiant intensity decreases over time due to current flowing in the infrared LED. When designing circuits, take into account the change in radiant intensity over time.





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20070701-EN

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